TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSIII)

2SK2611

DC-DC Converter, Relay Drive and Motor Drive Applications

• Low drain-source ON-resistance : RDS (ON) = 1.2Ω (typ.)

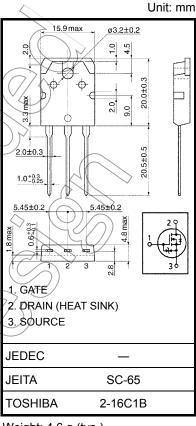
• High forward transfer admittance $|Y_{fs}| = 7.0 \text{ S (typ.)}$

• Low leakage current $: I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 720 \text{ V)}$

• Enhancement-mode : $V_{th} = 2.0 \text{ to } 4.0 \text{ V (VDS} = 10 \text{ V, ID} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteris	etics	Symbol	Rating	(Vinit)
Drain-source voltage		V_{DSS}	900	A
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V_{DGR}	900	×
Gate-source voltage		V_{GSS}	±30	> v
Drain current	DC (Note 1)	ΙD	9	Α
	Pulse (Note 1)	I _{DP}	27	A
Drain power dissipation	n (Tc = 25°C)	PD	150	/\w
Single pulse avalanche	e energy (Note 2)	E _A \$	663	É
Avalanche current		TAR	9	A
Repetitive avalanche e	nergy (Note 3)	((EAR))	15	/mJ
Channel temperature		Tch	150	~c
Storage temperature ra	nge	T _{stg}	-55 to 150	°C



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semisonductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics Symbol	Max	Unit
Thermal resistance, channel to case Rth (ch-c)	0.833	°C/W
Thermal resistance, channel to ambient R _{th (ch-a)}	50	°C/W

Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 15 mH, R_G = 25 Ω , I_{AR} = 9 A

Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device.

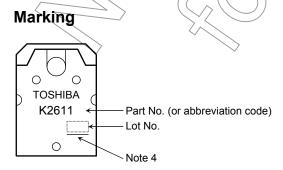
Please handle with caution.

Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	irrent	I _{GSS}	V _{GS} = ±30 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 720 V, V _{GS} = 0 V	//	_	100	μΑ
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	900		_	V
Gate threshold v	oltage/	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) >_	4.0	V
Drain-source O	N-resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 4 A	<u> </u>	1.2	1.4	Ω
Forward transfer	r admittance	Y _{fs}	V _{DS} = 15 V, I _D = 4 A	3.0	7.0	_	S
Input capacitano	e	C _{iss}		\	2040	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		45	_	pF
Output capacita	nce	Coss		_	190	_	
Switching time	Rise time	t _r	V _{GS} OV T D=4A V _{out}	- (25	\ <u>\</u>	
	Turn-on time	t _{on}	$R_{L} = \frac{100\Omega}{100\Omega}$		60) _	20
	Fall time	t _f	V _{DD} ≒400V		20	_	ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\rm W} = 10 \mu \rm s$		95	_	
Total gate charg plus gate-drain)		Qg			58		
Gate-source charge Q _{gs}		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 9 \text{ A}$	_	32	_	nC
Gate-drain ("mil	ler") Charge	Qgd		_	26	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	9	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	27	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 9 A, V _{GS} = 0 V	_	_	-1.9	V
Reverse recovery time	t _{rr}	I _{DR} = 9 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs	_	1.6	_	μs
Reverse recovery charge	Qrr	1DR - 9 A, VGS - 0 V, diDR / dt - 100 A / μs	_	20	_	μC

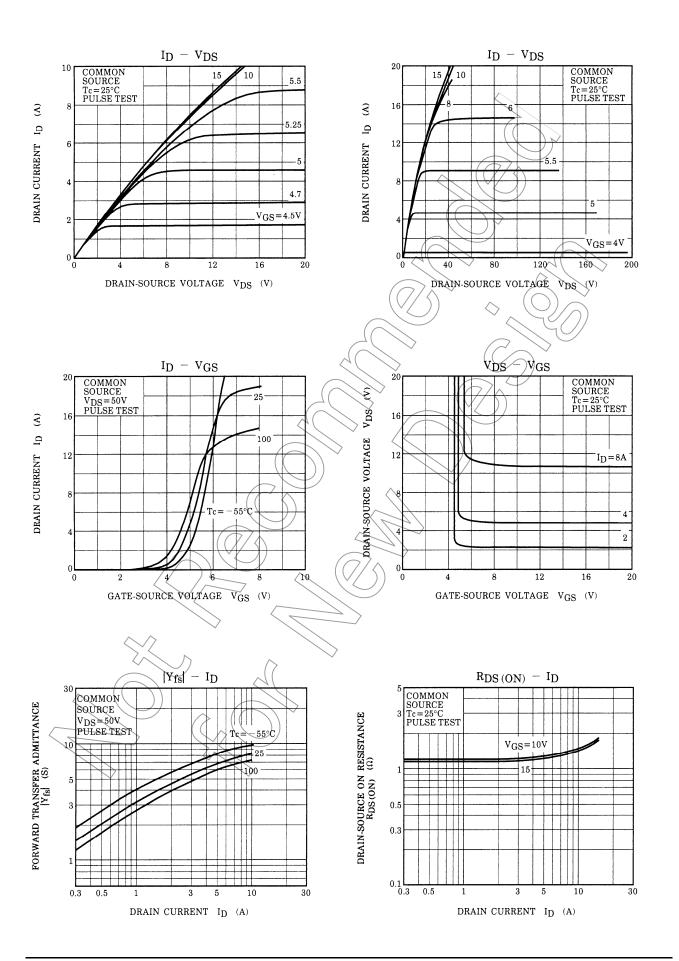


Note 4: A line under a Lot No. identifies the indication of product Labels.

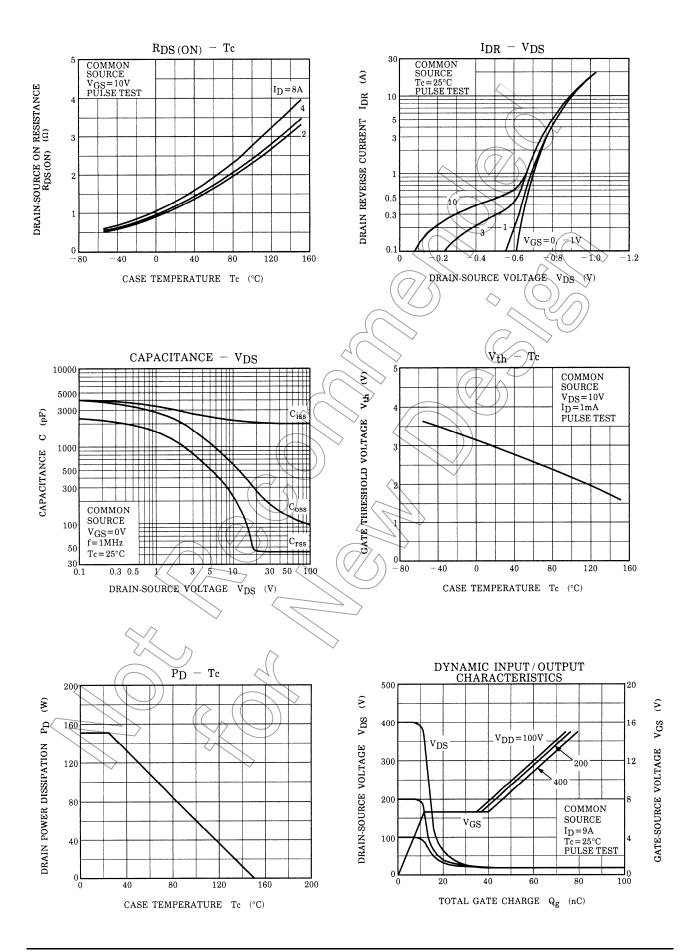
Not underlined: [[Pb]]/INCLUDES > MCV

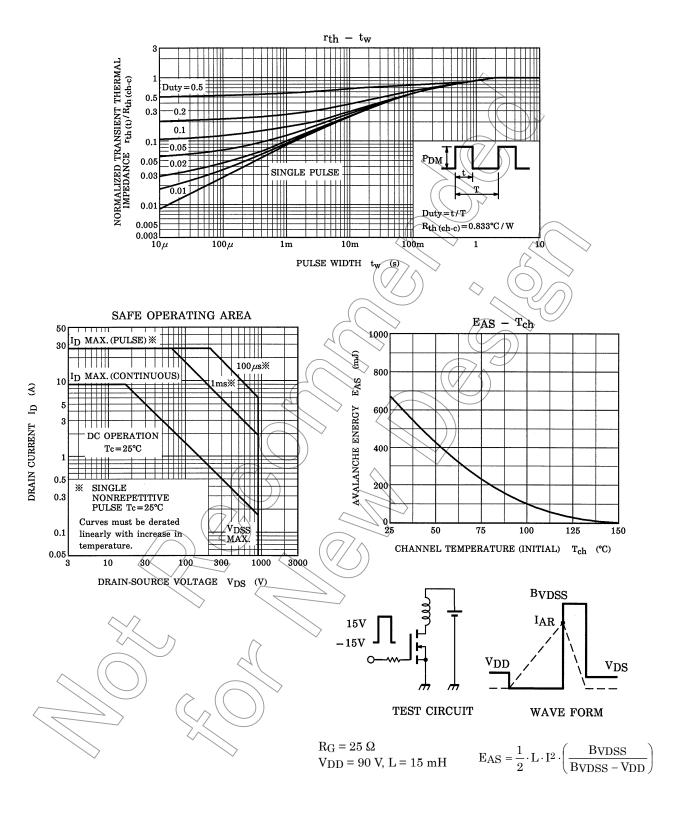
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



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